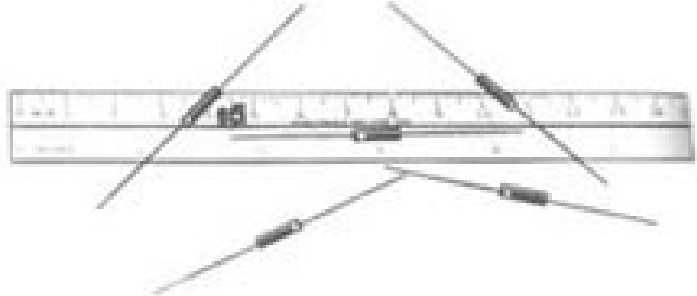




DL 300 DL1200

FAST RECOVERY HIGH VOLTAGE 25mA MINIATURE SILICON RECTIFIERS

- SMALL SIZE MOLDED PACKAGE
- PRV 3,000 TO 12,000 VOLTS
- 1.0 INCH MIN. LEADS
- LOW LEAKAGE



EDI Type	PRV Volts
DL300	3,000
DL500	5,000
DL800	8,000
DL1000	10,000
DL1200	12,000

ELECTRICAL CHARACTERISTICS (at $T_A=25^\circ\text{C}$ Unless Otherwise Specified)

Average Rectified Forward Current @ 50°C , I_o	25 mA
Max. Peak Surge Current, I_{FSM} (8.3ms)	3 Amp
Max. Reverse Recovery T_{rr} (Fig.4)	150nanosec
Max. Forward Voltage Drop @ 25mA, V_F	26Volts
Max. DC Reverse Current @ PRV and 25°C , I_R	1 μA
Max. DC Reverse Current @ PRV and 100°C , I_R	25 μA
Ambient Operating Temperature Range, T_A	-55°C to $+125^\circ\text{C}$
Storage Temperature Range, T_{STG}	-55°C to $+150^\circ\text{C}$

NOTES:

- 1.It is recommended that a proper heat sink be used on the terminals of this device between the body and soldering point to prevent damage from excess heat.
- 2.If operated over 10,000v/inch in length, devices should be immersed in oil or ree - ncapsulated.

EDI reserves the right to change these specifications at any time without notice.

FIG.1

OUTPUT CURRENT vs AMBIENT TEMPERATURE

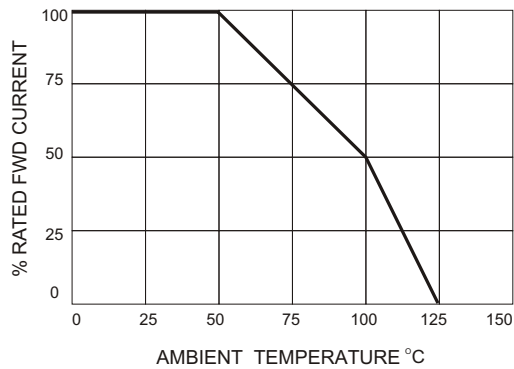


FIG.2

NON-REPETITIVE SURGE CURRENT

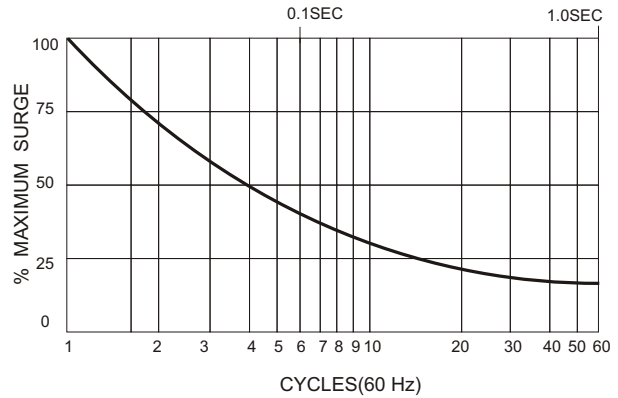


FIG.3
MECHANICAL

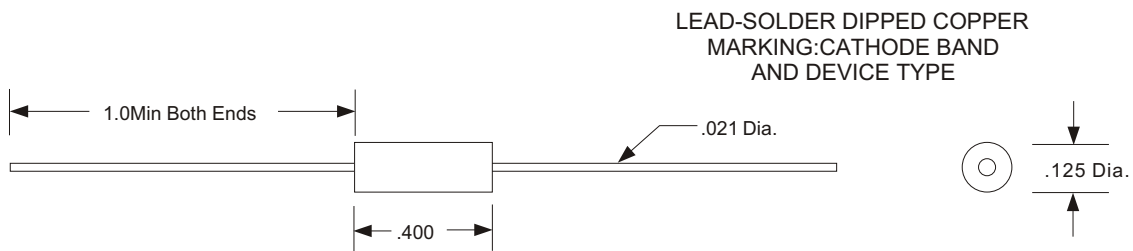
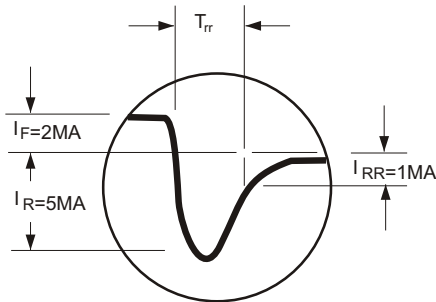


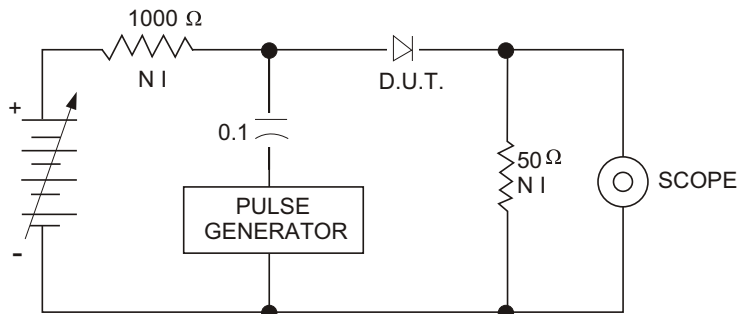
FIG.4
REVERSE RECOVERY TEST METHOD

RECOVERY WAVE FORM



WAVE FORMS

RECOVERY WAVE FORM



CIRCUIT